

# 2SC460, 2SC461

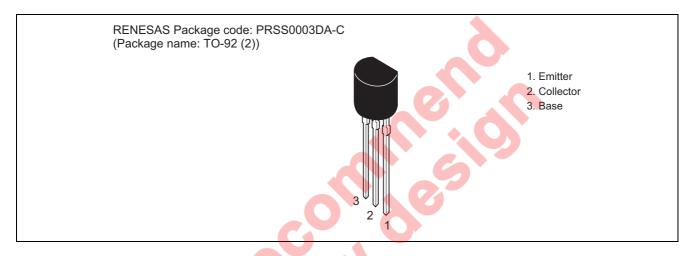
## Silicon NPN Epitaxial Planar

REJ03G0682-0200 (Previous ADE-208-1046) Rev.2.00 Aug.10.2005

### **Application**

- 2SC460 high frequency amplifier, mixer
- 2SC461 VHF amplifier, mixer

#### **Outline**



## **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

Item	Symbol	2SC460	2SC461	Unit
Collector to base voltage	V <sub>CBO</sub>	30	30	V
Collector to emitter voltage	V <sub>CEO</sub>	30	30	V
Emitter to base voltage	V <sub>EBO</sub>	5	5	V
Collector current	I <sub>C</sub>	100	100	mA
Collector power dissipation	Pc	200	200	mW
Junction temperature	Tj	150	150	°C
Storage temperature	Tstg	-55 to +150	-55 to +150	°C

#### **Electrical Characteristics**

 $(Ta = 25^{\circ}C)$ 

		2SC460 2SC461							
Item	Symbol	Min	Тур	Max	Min	Тур	Max	Unit	Test conditions
Collector to base	V <sub>(BR)CBO</sub>	30	_	_	30	_	_	V	$I_C = 10  \mu A,  I_E = 0$
breakdown voltage									
Collector to emitter	$V_{(BR)CEO}$	30		_	30	_	_	V	$I_C = 1 \text{ mA}, R_{BE} = \infty$
breakdown voltage									
Emitter to base	$V_{(BR)EBO}$	5	_	_	5	_	_	V	$I_E = 10 \mu A, I_C = 0$
breakdown voltage									
Collector cutoff current	I <sub>CBO</sub>			0.5	_	—	0.5	μΑ	$V_{CB} = 18 \text{ V}, I_{E} = 0$
Emitter cutoff current	I <sub>EBO</sub>		_	0.5	_	_	0.5	μΑ	$V_{EB} = 2 \text{ V}, I_{C} = 0$
Base to emitter voltage	$V_{BE}$		0.63	0.75	_	0.63	0.75	V	$V_{CE} = 12 \text{ V}, I_{C} = 2 \text{ mA}$
DC current transfer ratio	h <sub>FE</sub> *1	100	_	200	35	_	200		$V_{CE} = 12 \text{ V}, I_{C} = 2 \text{ mA}$
Collector to emitter	V <sub>CE(sat)</sub>	_	0.6	1.1	_	0.6	1.1	V	$I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$
saturation voltage									
Gain bandwidth product	f⊤		230		_	230		MHz	$V_{CE} = 12 \text{ V}, I_{C} = 2 \text{ mA}$
Collector output	Cob	_	1.8	3.5	_	1.8	3.5	pF	$V_{CB} = 10 \text{ V}, I_E = 0,$
capacitance									f = 1 MHz
10.7 MHz power gain	PG	26	29	_	_	-	_	dB	$V_{CE} = 6 \text{ V}, I_{E} = -1 \text{ mA}$
									f = 10.7 MHz
100 MHz power gain	PG		_	_	13	17	$\sim$	dB	$V_{CE} = 6 \text{ V}, I_{E} = -1 \text{ mA}$
									f = 100 MHz
Noise figure	NF		2.0	_	7	-0		dB	$V_{CE} = 6 \text{ V}, I_{E} = -1 \text{ mA}$
									f = 1MHz
									$R_g = 500\Omega$

Note: 1. The 2SC461 is grouped by h<sub>FE</sub> as follows.

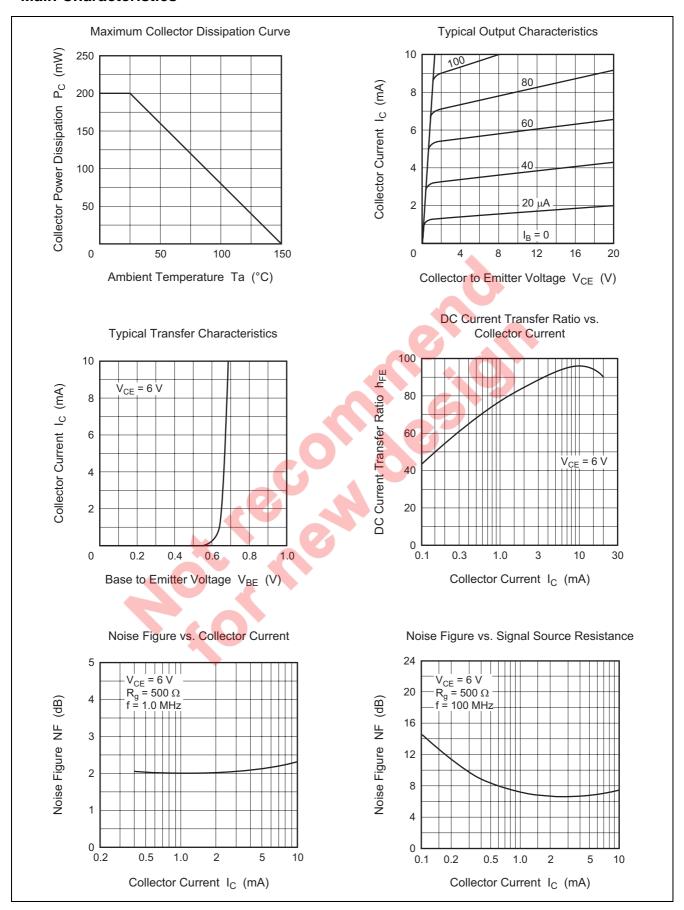
В	С
60 to 120	100 to 200

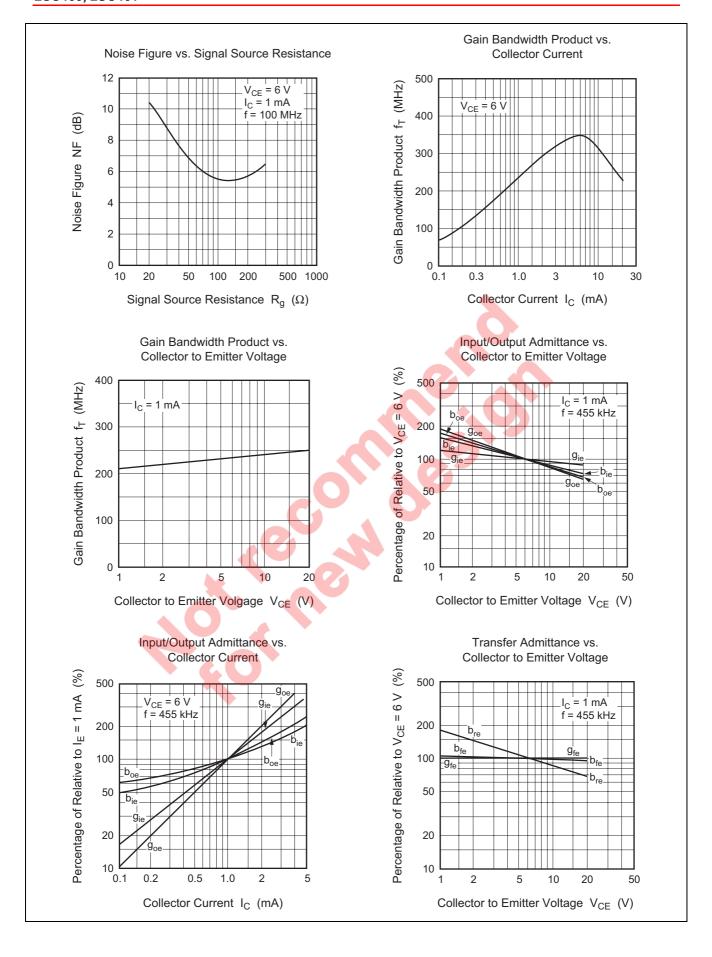
## **Small Signal y Parameters**

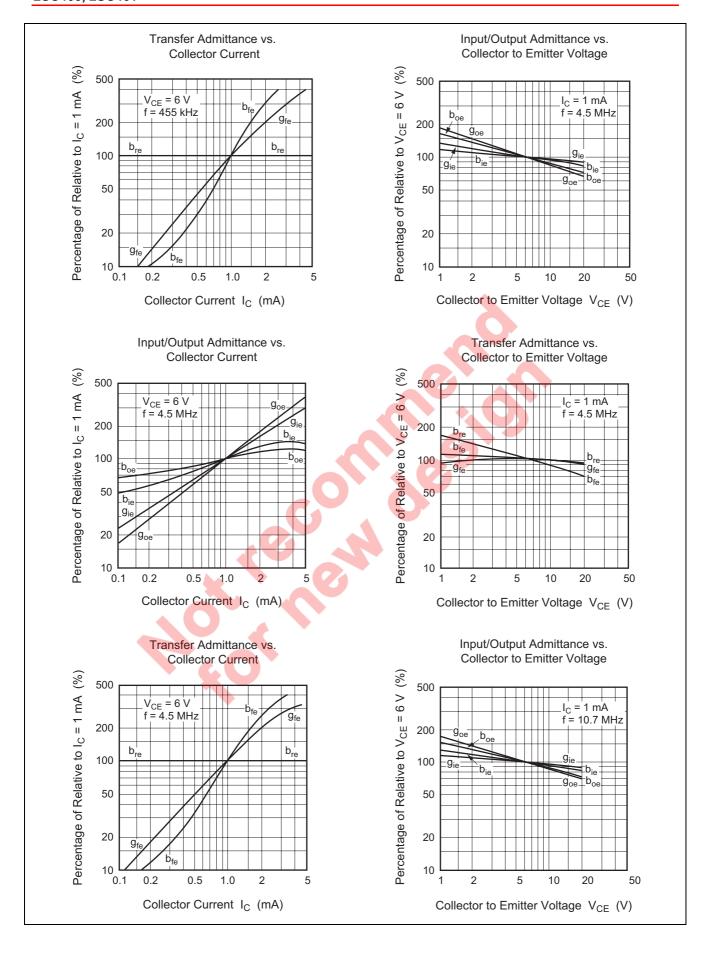
 $(V_{CE} = 6 \text{ V}, I_C = 1 \text{ mA, Emitter Common})$ 

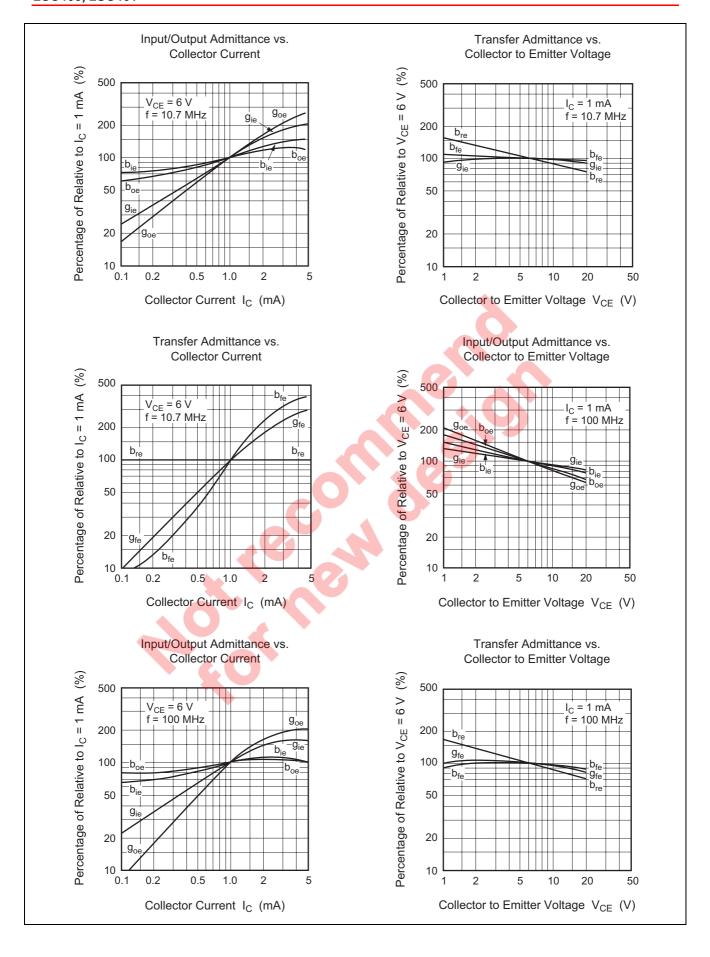
			T		ı	
			2SC460A,	2SC460B,	2SC460C,	
Item	Symbol	f	2S461A	2SC461B	2SC461C	Unit
Input admittance	yie	455 kHz	0.58 + j0.074	0.42 + j0.068	0.30 + j0.051	mS
		4.5 MHz	0.65 + j0.79	0.50 + j0.7	0.35 + j0.57	
		10.7 MHz	0.91 + j2.0	0.61 + j1.9	0.39 + j1.3	
		100 MHz	7.4 + j14	5.6 + j12	3.8 + j6.0	
Reverse transfer admittance	yre	455 kHz	-j0.003	-j0.003	-j0.003	mS
		4.5 MHz	-j0.04	−j0.04	-j0.04	
		10.7 MHz	−j0.13	−j0.13	−j0.13	
		100 MHz	−j1.0	−j1.0	−j1.0	
Forward transfer admittance	yfe	455 kHz	38 – j0.1	37 – j0.1	37 – j0.2	mS
		4.5 MHz	35 – j1.0	35 – j1.2	34 – j1.8	
		10.7 MHz	34 – j2.5	34 – j2.5	33 – j4.5	
		100 MHz	28 – j20	28 – j19	20 – j19	
Output admittance	yoe	455 kHz	0.0098 + j0.009	0.013 + j0.009	0.016 + j0.012	mS
		4.5 MHz	0.02 + j0.09	0.023 + j0.092	0.03 + j0.10	
		10.7 MHz	0.11 + j0.4	0.11 + j0.4	0.12 + j0.4	
		100 MHz	0.40 + j1.7	0.50 + j2.0	0.83 + j2.0	

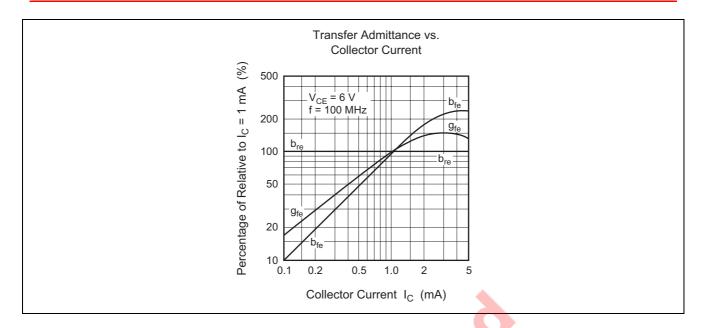
#### **Main Characteristics**



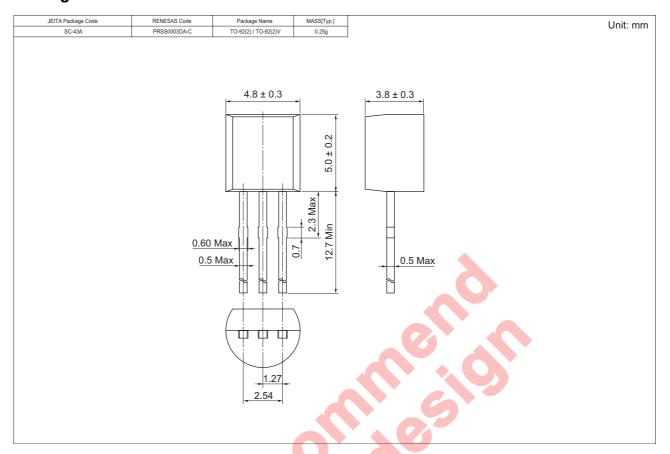








## **Package Dimensions**



## **Ordering Information**

Part Name	9	Quantity	Shipping Container
2SC460CTZ	2500		Hold Box, Radial Taping
2SC461BTZ			
2SC461CTZ			

Note: For some grades, production may be terminated. Please contact the Renesas sales office to check the state of production before ordering the product.

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